SEMICONDUCTOR

E1A THRU E1M

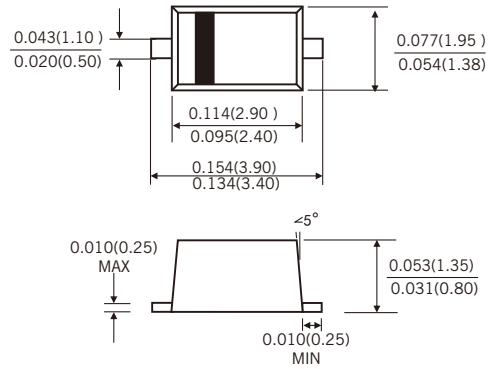
GLASS PASSIVATED SUPER FAST RECOVERY RECTIFIER

Reverse Voltage: 50 to 1000 Volts
Forward Current:1.0Ampere

FEATURES

- Glass passivated junction
- For Surface Mount Applications, Easy to pick and place
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- High temperature soldering guaranteed:260℃/10 seconds at terminals,
- Component in accordance to RoHS 2015/863/EU

SOD-123FL



Dimensions in inches and (millimeters)

MECHANICAL DATA

- Case: SOD-123FL molded plastic
- Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.01 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Rating at 25°C ambient temperature unless otherwise specified.Single phase ,half wave ,60Hz,resistive or inductive load. For capacitive load,derate current by 20%.)

	Symbols	E1A	E1B	E1D	E1G	E1J	E1K	E1M	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at T_L=100°C	$I_{(AV)}$	1.0							Amps
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	30. 0							Amps
Maximum Instantaneous Forward Voltage at 1.0 A	V_F	0.95			1.3	1.7	2. 2	2. 9	Volts
Maximum DC Reverse Current T_A=25°C	I_R	5.0							μA
at rated DC blocking voltage T_A=125°C		100							
Thermal resistance from junction to ambient	$R_{\theta JA}$	150							℃/W
Maximum reverse recovery time(Note1)	t_{rr}	35							ns
Typical junction capacitance(Note2)	C_J	15.0							pF
Operating junction and storage temperature range	T_J T_{STG}	-55 to+150							°C

Note: 1.Test conditions: I_F=0.5A,I_R=1.0A,I_{RR}=0.25A.

2.Measured at 1MHz and applied reverse voltage of 4.0 Volts D.C.

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

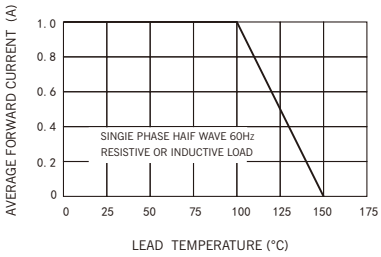


FIG.2-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

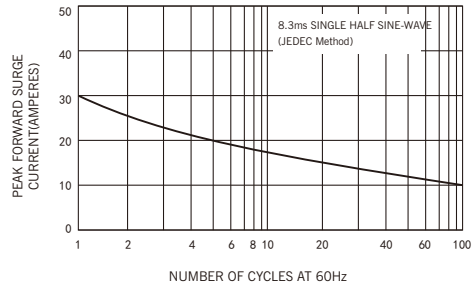


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

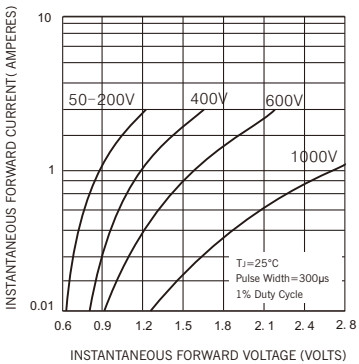


FIG.4-TYPICAL REVERE CHARACTERISTICS

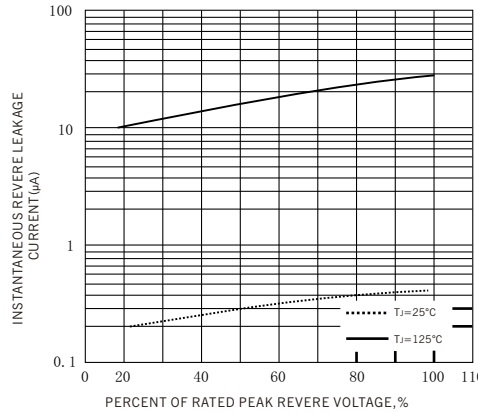


FIG.5-TYPICAL JUNCTION CAPACITANCE

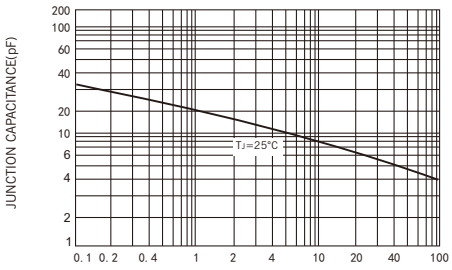
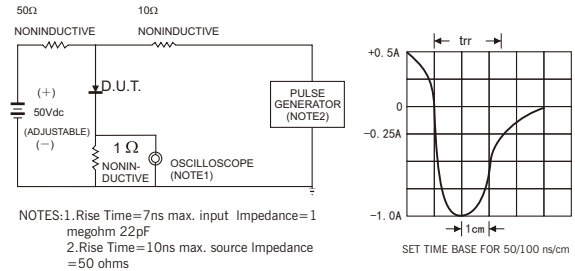


FIG.6-TEST CIRCUIT DIAGRAM AND REVERE RECOVERY TIME CHARACTERISTIC



NOTES:1.Rise Time=7ns max. input Impedance=1 megohm 22pF
2.Rise Time=10ns max. source Impedance =50 ohms

Friendship Reminder

■ JiNan JingHeng（hereinafter referred to as JH） reserves the right to make changes to this document and its products and specifications at anytime without notice.

■ Customers should obtain and confirm the latest product information and specifications before final design, purchase or use.

■ JH makes no warranty, representation or guarantee regarding the suitability ofi ts products for any particular purpose, nor does JH assume any liability for application assistance or customer product design.

■ JH does not warrant or accept any liability with products which are purchased or used for any unintended or unauthorized application.

■ No license is granted by implication or otherwise under any intellectual property rights of JH.

■ JH's products are not authorized for use as critical components in life support devices or systems without express written approval of JH.